

ABSTRACT OF DISCLOSURE

A gate line GL is set to an H level to switch on a selection TFT (10) and a short-circuiting TFT (16). A current corresponding to data (data current (negative)) is applied to a data line (Data).
5 In this manner, a current corresponding to the data current flows through a voltage converter TFT (12) and a driver TFT (14) and light is emitted from an organic EL element (50). A gate voltage of the voltage converter TFT (12) and the driver TFT (14) in this process
10 is stored in a storage capacitor (C). Even after the data current is switched off and the selection TFT (10) and the short-circuiting TFT (16) are switched off, the driver TFT (14) continues to apply a current. After a predetermined emission period elapses, an erase line (ESL) is driven to switch an erase TFT (18) on to discharge
15 the storage capacitor (C) and switch the driver TFT (14) off.